## BAV19WS, BAV20WS, BAV21WS

## Silicon Epitaxial Planar Diodes

High Voltage Switching Diode

## Features

- Fast switching speed
- Surface mount package ideally suited for automatic insertion

|  | BAV19WS | BAV20WS | BAV21WS |
| :---: | :---: | :---: | :---: |
| MARKING | A8 | T2 | T3 |

Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ )

| Parameter |  | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Repetitive Peak Reverse Voltage | BAV19WS BAV20WS BAV21WS | $\mathrm{V}_{\text {RRM }}$ | $\begin{aligned} & 120 \\ & 200 \\ & 250 \end{aligned}$ | V |
| Reverse Voltage | BAV19WS BAV20WS BAV21WS | $\mathrm{V}_{\mathrm{R}}$ | $\begin{aligned} & 100 \\ & 150 \\ & 200 \end{aligned}$ | V |
| Average Rectified Forward Current |  | $\mathrm{I}_{\text {(AV) }}$ | 200 | mA |
| Forward Continuous Current |  | $\mathrm{I}_{\text {FM }}$ | 400 | mA |
| Repetitive Peak Forward Current |  | $\mathrm{I}_{\text {FRM }}$ | 625 | mA |
| Non-Repetitive Peak Forward Surge Current | $\begin{aligned} & \text { at } \mathrm{t}=1 \mu \mathrm{~s} \\ & \text { at } \mathrm{t}=1 \mathrm{~s} \end{aligned}$ | $I_{\text {FSM }}$ | $\begin{aligned} & 2.5 \\ & 0.5 \end{aligned}$ | A |
| Power Dissipation |  | $\mathrm{P}_{\text {tot }}$ | 200 | mW |
| Operating and Storage Temperature Range |  | $\mathrm{T}_{\mathrm{j},} \mathrm{T}_{\text {stg }}$ | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |

Characteristics at $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$

| Parameter |  | Symbol | Min. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Reverse Breakdown Voltage at $I_{R}=100 \mu \mathrm{~A}$ | BAV19WS BAV20WS BAV21WS | $\mathrm{V}_{(\mathrm{BR}) \mathrm{R}}$ | $\begin{aligned} & 120 \\ & 200 \\ & 250 \end{aligned}$ | - | V |
| $\begin{aligned} & \text { Reverse Current } \\ & \text { at } \mathrm{V}_{\mathrm{R}}=100 \mathrm{~V} \\ & \text { at } \mathrm{V}_{\mathrm{R}}=150 \mathrm{~V} \\ & \text { at } \mathrm{V}_{\mathrm{R}}=200 \mathrm{~V} \\ & \hline \end{aligned}$ | BAV19WS BAV20WS BAV21WS | $I_{R}$ |  | $\begin{aligned} & 100 \\ & 100 \\ & 100 \\ & \hline \end{aligned}$ | nA |
| Forward Voltage at $I_{F}=100 \mathrm{~mA}$ at $I_{F}=200 \mathrm{~mA}$ |  | $V_{F}$ | - | $\begin{gathered} 1 \\ 1.25 \\ \hline \end{gathered}$ | V |
| Total Capacitance at $V_{R}=0, f=1 \mathrm{MHz}$ |  | $\mathrm{C}_{\text {T }}$ | - | 5 | pF |
| Reverse Recovery Time at $I_{F}=I_{R}=30 \mathrm{~mA}, \mathrm{I}_{\mathrm{RR}}=0.1 \mathrm{XI}, \mathrm{I}_{\mathrm{L}}=100 \Omega$ |  | $\mathrm{t}_{\mathrm{rr}}$ | - | 50 | ns |



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Fig. 2 Typical Reverse Characteristics
$\mathrm{T}_{\mathrm{A}}$, AMBIENT TEMPERATURE ( ${ }^{\circ} \mathrm{C}$ )
Fig. 4 Power Derating Curve, Total Package

## PACKAGE OUTLINE

## Plastic surface mounted package;



2 leads


| UNIT | $A$ | $b_{p}$ | $C$ | $D$ | $E$ | $H E$ | $A_{1}$ | $L_{p}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| mm | 1.20 | 0.40 | 0.15 | 1.80 | 1.35 | 2.80 | 0.10 | 0.50 |
|  | 0.90 | 0.25 | 0.10 | 1.60 | 1.15 | 2.30 | 0.01 | 0.20 |

